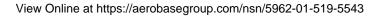
NSN 5962-01-519-5543

Memory Microcircuit - Page 1 of 1





Operating Tempurature Range:

-40.0/+85.0 degrees celsius

Features Provided:

Electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Pin grid array

Criticality Code Justification:

Cbbl

Product Name:

High-speed 8 k x 16 dual port static ram

Voltage Rating And Type Per Characteristic:

4.5 volts total supply and 5.5 volts total supply

Memory Device Type:

Ram

Memory Capacity:

8k x 16

Terminal Type And Quantity:

84 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0